

Data sheet acquired from Harris Semiconductor SCHS187C

January 1998 - Revised July 2003

Features

- Common Latch-Enable Control
- Common Three-State Output Enable Control
- Buffered Inputs
- Three-State Outputs
- Bus Line Driving Capacity
- Typical Propagation Delay = 13ns at V_{CC} = 5V, $C_L = 15 pF$, $T_A = 25^{\circ}C$ (Data to Output)
- Fanout (Over Temperature Range)
 - Standard Outputs 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: NIL = 30%, NIH = 30% of V_{CC} at $V_{CC} = 5V$
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, $V_{IL} = 0.8V (Max), V_{IH} = 2V (Min)$
 - CMOS Input Compatibility, $I_I \leq 1\mu A$ at V_{OI} , V_{OH}

CD54/74HC533, CD54/74HCT533, CD54/74HC563, CD74HCT563

High-Speed CMOS Logic Octal Inverting Transparent Latch, Three-State Outputs

Description

The 'HC533, 'HCT533, 'HC563, and CD74HCT563 are high-speed Octal Transparent Latches manufactured with silicon gate CMOS technology. They possess the low power consumption of standard CMOS integrated circuits, as well as the ability to drive 15 LSTTL devices.

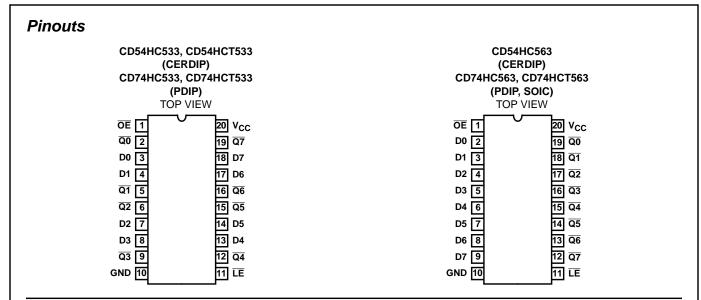
The outputs are transparent to the inputs when the latch enable (\overline{LE}) is high. When the latch enable (\overline{LE}) goes low the data is latched. The output enable (\overline{OE}) controls the three-state outputs. When the output enable (\overline{OE}) is high the outputs are in the high impedance state. The latch operation is independent of the state of the output enable.

The 'HC533 and 'HCT533 are identical in function to the 'HC563 and CD74HCT563 but have different pinouts. The 'HC533 and 'HCT533 are similar to the 'HC373 and 'HCT373; the latter are non-inverting types.

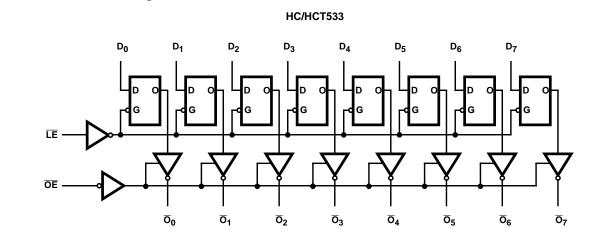
Ordering Information

| PART NUMBER | TEMP. RANGE (^o C) | PACKAGE |
|---------------|----------------------------------|--------------|
| CD54HC533F3A | -55 to 125 | 20 Ld CERDIP |
| CD54HC563F3A | -55 to 125 | 20 Ld CERDIP |
| CD54HCT533F3A | -55 to 125 | 20 Ld CERDIP |
| CD74HC533E | -55 to 125 | 20 Ld PDIP |
| CD74HC563E | -55 to 125 | 20 Ld PDIP |
| CD74HC563M | -55 to 125 | 20 Ld SOIC |
| CD74HCT533E | -55 to 125 | 20 Ld PDIP |
| CD74HCT563E | -55 to 125 | 20 Ld PDIP |
| CD74HCT563M | -55 to 125 | 20 Ld SOIC |

CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures. Copyright © 2003, Texas Instruments Incorporated



Functional Block Diagram



TRUTH TABLE

| OUTPUT ENABLE | LATCH ENABLE | DATA | Q OUTPUT |
|---------------|--------------|------|----------|
| L | Н | Н | L |
| L | Н | L | н |
| L | L | l | Н |
| L | L | h | L |
| Н | Х | Х | Z |

H = High Voltage Level, L = Low Voltage Level, X = Don't Care, Z = High Impedance State, I = Low voltage level one set-up time prior to the high to low latch enable transition, h = High voltage level one set-up time prior to the high to low latch enable transition.

Absolute Maximum Ratings

| DC Supply Voltage, V _{CC} 0.5V to 7V DC Input Diode Current, I _{IK} |
|---------------------------------------------------------------------------------------|
| For $V_{l} < -0.5V$ or $V_{l} > V_{CC} + 0.5V$ |
| DC Output Diode Current, IOK |
| For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$ |
| DC Drain Current, per Output, I _O |
| For -0.5V < V _O < V _{CC} + 0.5V±35mA |
| DC Output Source or Sink Current per Output Pin, IO |
| For $V_0 > -0.5V$ or $V_0 < V_{CC} + 0.5V$ ±25mA |
| DC V _{CC} or Ground Current, I _{CC} ±50mA |
| |

Operating Conditions

| Temperature Range, T_A |
|----------------------------------------------|
| Supply Voltage Range, V _{CC} |
| HC Types |
| HCT Types |
| DC Input or Output Voltage, VI, VO 0V to VCC |
| Input Rise and Fall Time |
| 2V |
| 4.5V 500ns (Max) |
| 6V |
| |

Thermal Information

| Thermal Resistance (Typical, Note 1) | θ _{JA} (^o C/W) |
|------------------------------------------|-----------------------------------------|
| E (PDIP) Package | . 69 |
| M (SOIC) Package | . 58 |
| Maximum Junction Temperature | 150 ⁰ C |
| Maximum Storage Temperature Range | 65 ^o C to 150 ^o C |
| Maximum Lead Temperature (Soldering 10s) | 300 ⁰ C |
| (SOIC - Lead Tips Only) | |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

| | | | ST ITIONS | | | 25°C -40°C | | -40 ⁰ C 1 | O 85 ⁰ C | -55 ⁰ С Т | O 125 ⁰ C | |
|-----------------------------|-----------------|---------------------------------------|---------------------|---------------------|------|------------|------|----------------------|---------------------|----------------------|----------------------|----|
| PARAMETER | SYMBOL | V _I (V) | I _O (mA) | V _{CC} (V) | MIN | TYP | MAX | MIN | MAX | MIN | MAX | |
| HC TYPES | | | _ | | | | | | _ | | | - |
| High Level Input | V _{IH} | - | - | 2 | 1.5 | - | - | 1.5 | - | 1.5 | - | V |
| Voltage | | | | 4.5 | 3.15 | - | - | 3.15 | - | 3.15 | - | V |
| | | | | 6 | 4.2 | - | - | 4.2 | - | 4.2 | - | V |
| Low Level Input | V _{IL} | - | - | 2 | - | - | 0.5 | - | 0.5 | - | 0.5 | V |
| Voltage | | | | 4.5 | - | - | 1.35 | - | 1.35 | - | 1.35 | V |
| | | | | 6 | - | - | 1.8 | - | 1.8 | - | 1.8 | V |
| High Level Output | V _{OH} | V _{IH} or | -0.02 | 2 | 1.9 | - | - | 1.9 | - | 1.9 | - | V |
| Voltage CMOS Loads | | VIL | -0.02 | 4.5 | 4.4 | - | - | 4.4 | - | 4.4 | - | V |
| 0 | | | -0.02 | 6 | 5.9 | - | - | 5.9 | - | 5.9 | - | V |
| High Level Output | | | -6 | 4.5 | 3.98 | - | - | 3.84 | - | 3.7 | - | V |
| Voltage TTL Loads | | | -7.8 | 6 | 5.48 | - | - | 5.34 | - | 5.2 | - | V |
| Low Level Output | V _{OL} | V _{IH} or V _{IL} | 0.02 | 2 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| Voltage CMOS Loads | | | 0.02 | 4.5 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| | | | 0.02 | 6 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| Low Level Output | | | 6 | 4.5 | - | - | 0.26 | - | 0.33 | - | 0.4 | V |
| Voltage TTL Loads | | | 7.8 | 6 | - | - | 0.26 | - | 0.33 | - | 0.4 | V |
| Input Leakage Current | lı | V _{CC} or GND | - | 6 | - | - | ±0.1 | - | ±1 | - | ±1 | μA |
| Quiescent Device Current | Icc | V _{CC} or GND | 0 | 6 | - | - | 8 | - | 80 | - | 160 | μA |

CD54/74HC533, CD54/74HCT533, CD54/74HC563, CD74HCT563

| | | | ST ITIONS | | 25 ⁰ C | | | -40 ⁰ C TO 85 ⁰ C | | -55°C TO 125°C | | |
|----------------------------------------------------------------------|------------------------------|---------------------------------------|-----------------------------------------------|---------------------|-------------------|-----|------|-----------------------------------------|------|----------------|-----|-------|
| PARAMETER | SYMBOL | V _I (V) | I _O (mA) | V _{CC} (V) | MIN | TYP | MAX | MIN | MAX | MIN | MAX | UNITS |
| Three-State Leakage Current | - | V _{IL} or V _{IH} | V _O = V _{CC} or GND | 6 | - | - | ±0.5 | - | ±5 | - | ±10 | μA |
| HCT TYPES | | | | | | | | | | | | |
| High Level Input Voltage | VIH | - | - | 4.5 to 5.5 | 2 | - | - | 2 | - | 2 | - | V |
| Low Level Input Voltage | V _{IL} | - | - | 4.5 to 5.5 | - | - | 0.8 | - | 0.8 | - | 0.8 | V |
| High Level Output Voltage CMOS Loads | V _{OH} | V _{IH} or V _{IL} | -0.02 | 4.5 | 4.4 | - | - | 4.4 | - | 4.4 | - | V |
| High Level Output Voltage TTL Loads | | | -6 | 4.5 | 3.98 | - | - | 3.84 | - | 3.7 | - | V |
| Low Level Output Voltage CMOS Loads | V _{OL} | V _{IH} or V _{IL} | 0.02 | 4.5 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| Low Level Output Voltage TTL Loads | | | 6 | 4.5 | - | - | 0.26 | - | 0.33 | - | 0.4 | V |
| Input Leakage Current | lı | V _{CC} to GND | - | 5.5 | - | - | ±0.1 | - | ±1 | - | ±1 | μA |
| Quiescent Device Current | Icc | V _{CC} or GND | 0 | 5.5 | - | - | 8 | - | 80 | - | 160 | μA |
| Three-State Leakage Current | - | V _{IL} or V _{IH} | V _O = V _{CC} or GND | 5.5 | - | - | ±0.5 | - | ±5 | - | ±10 | μΑ |
| Additional Quiescent Device Current Per Input Pin: 1 Unit Load | ΔI _{CC} (Note 2) | V _{CC} -2.1 | - | 4.5 to 5.5 | - | 100 | 360 | - | 450 | - | 490 | μΑ |

NOTE:

2. For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

HCT Input Loading Table

| INPUT | UNIT LOADS |
|---------|------------|
| D0 - D7 | 0.15 |
| LE | 0.30 |
| ŌĒ | 0.55 |

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g., 360µA max at 25°C.

CD54/74HC533, CD54/74HCT533, CD54/74HC563, CD74HCT563

Prerequisite For Switching Specifications

| | | TEST | v _{cc} | | 25 ⁰ C | | -40 ⁰ C T | O 85 ⁰ C | -55°C TO 125°C | | |
|-------------------------------------------------|----------------|------------|-----------------|-----|-------------------|-----|----------------------|---------------------|----------------|-----|-------|
| PARAMETER | SYMBOL | CONDITIONS | (V) | MIN | TYP | MAX | MIN | MAX | MIN | MAX | UNITS |
| HC TYPES | | | | | | | | | | | |
| LE Pulse Width | t _W | - | 2 | 80 | - | - | 100 | - | 120 | - | ns |
| | | | 4.5 | 16 | - | - | 20 | - | 24 | - | ns |
| | | | 6 | 14 | - | - | 17 | - | 20 | - | ns |
| Set-up Time Data to LE | ts∪ | - | 2 | 50 | - | - | 65 | - | 75 | - | ns |
| | | | 4.5 | 10 | - | - | 13 | - | 15 | - | ns |
| | | | 6 | 9 | - | - | 11 | - | 13 | - | ns |
| Hold Time, Data to $\overline{\text{LE}}$ | t _H | - | 2 | 35 | - | - | 45 | - | 55 | - | ns |
| (533) | | | 4.5 | 7 | - | - | 9 | - | 11 | - | ns |
| | | | 6 | 6 | - | - | 8 | - | 7 | - | ns |
| Hold Time, Data to $\overline{\text{LE}}$ | t _H | - | 2 | 4 | - | - | 4 | - | 4 | - | ns |
| (563) | | | 4.5 | 4 | - | - | 4 | - | 4 | - | ns |
| | | | 6 | 4 | - | - | 4 | - | 4 | - | ns |
| HCT TYPES | • | • | | | | | | | | | |
| LE Pulse Width | t _w | - | 4.5 | 16 | - | - | 20 | - | 24 | - | ns |
| Set-up Time Data to LE | tw | - | 4.5 | 10 | - | - | 13 | - | 15 | - | ns |
| Hold Time, Data to $\overline{\text{LE}}$ (533) | t _H | - | 4.5 | 8 | - | - | 10 | - | 12 | - | ns |
| Hold Time, Data to LE (563) | t _H | - | 4.5 | 5 | - | - | 5 | - | 5 | - | ns |

Switching Specifications Input t_r, t_f = 6ns

| | | TEST | | 25 ⁰ C | | -40 ⁰ C TO 85 ⁰ C | -55 ⁰ C TO 125 ⁰ C | |
|---------------------------------------------|-------------------------------------|-----------------------|---------------------|-------------------|-----|-----------------------------------------|---------------------------------------------|----|
| PARAMETER | SYMBOL | CONDITIONS | V _{CC} (V) | TYP | MAX | МАХ | MAX | |
| HC TYPES | | | | | | | | |
| Propagation Delay, | t _{PLH} , t _{PHL} | C _L = 50pF | 2 | - | 165 | 205 | 250 | ns |
| Data to Qn (HC533) | | | 4.5 | - | 33 | 41 | 50 | ns |
| X , | | | 6 | - | 28 | 35 | 43 | ns |
| | | C _L = 15pF | 5 | 13 | - | - | - | ns |
| Propagation Delay, Data to Qn (HC563) | ^t PLH, ^t PHL | C _L = 50pF | 2 | - | 150 | 190 | 225 | ns |
| | | | 4.5 | - | 30 | 38 | 45 | ns |
| | | | 6 | - | 26 | 33 | 38 | ns |
| | | C _L = 15pF | 5 | 12 | - | - | - | ns |
| Propagation Delay, | ^t PLH, ^t PHL | C _L = 50pF | 2 | - | 175 | 220 | 265 | ns |
| LE to Qn (HC533) | | | 4.5 | - | 35 | 44 | 53 | ns |
| () | | | 6 | - | 30 | 37 | 45 | ns |
| | | C _L = 15pF | 5 | 14 | - | - | - | ns |
| Propagation Delay, | ^t PLH, ^t PHL | C _L = 50pF | 2 | - | 165 | 205 | 250 | ns |
| LE to Qn (HC563) | | | 4.5 | - | 33 | 41 | 50 | ns |
| (| | | 6 | - | 28 | 35 | 43 | ns |
| | | C _L = 15pF | 5 | 13 | - | - 1 | - | ns |

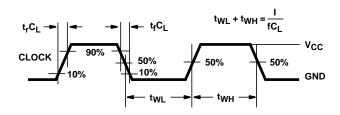
| | | TEST | | 25 | 5°C | -40 ⁰ C TO 85 ⁰ C | -55°C TO 125 [°] C | | |
|--------------------------------------------------|---------------------------------------|-----------------------|---------------------|-----|-----|-----------------------------------------|--------------------------------|----|--|
| PARAMETER | SYMBOL | CONDITIONS | V _{CC} (V) | TYP | MAX | МАХ | MAX | | |
| Enable Times | t _{PZH} , t _{PZL} | C _L = 50pF | 2 | - | 150 | 190 | 225 | ns | |
| (HC533) | | | 4.5 | - | 30 | 38 | 45 | ns | |
| | | | 6 | - | 26 | 33 | 38 | ns | |
| | | C _L = 15pF | 5 | 12 | - | - | - | ns | |
| Disable Times | tPHZ, tPLZ | C _L = 50pF | 2 | - | 150 | 190 | 225 | ns | |
| (HC533) | | | 4.5 | - | 30 | 38 | 45 | ns | |
| | | | 6 | - | 26 | 33 | 38 | ns | |
| | | C _L = 15pF | 5 | 12 | - | - | - | ns | |
| Enable and Disable Times | ^t PZH, ^t PZL, | C _L = 50pF | 2 | - | 150 | 190 | 225 | ns | |
| (HC563) | ^t PHZ, ^t PLZ | | 4.5 | - | 30 | 38 | 45 | ns | |
| | | | 6 | - | 26 | 33 | 38 | ns | |
| | | C _L = 15pF | 5 | 12 | - | - | - | ns | |
| Input Capacitance | Cl | - | - | - | 10 | 10 | 10 | pF | |
| Three-State Output Capacitance | C _O | - | - | - | 20 | 20 | 20 | pF | |
| Power Dissipation Capacitance (Notes 3, 4) | C _{PD} | - | 5 | 42 | - | - | - | pF | |
| HCT TYPES | | | | | | | | | |
| Propagation Delay, Data to Qn | t _{PLH} , t _{PHL} | C _L = 50pF | 4.5 | - | 34 | 43 | 51 | ns | |
| (HC/HCT533) | | C _L = 15pF | 5 | 14 | - | - | - | ns | |
| Propagation Delay, | t _{PLH} , t _{PHL} | C _L = 50pF | 4.5 | - | 30 | 38 | 45 | ns | |
| Data to Qn (HC/HCT563) | | C _L = 15pF | 5 | 12 | - | - | - | ns | |
| Propagation Delay, | t _{PLH} , t _{PHL} | C _L = 50pF | 4.5 | - | 38 | 48 | 57 | ns | |
| LE to Qn (HC/HCT533) | | C _L = 15pF | 5 | 16 | - | - | - | ns | |
| Propagation Delay, | t _{PZL} , t _{PZH} | C _L = 50pF | 4.5 | - | 35 | 44 | 53 | ns | |
| LE to Qn (HC/HCT563) | | C _L = 15pF | 5 | 14 | - | - | - | ns | |
| Enable Times | t _{PLZ} , t _{PZH} | C _L = 50pF | 4.5 | - | 35 | 44 | 53 | ns | |
| (HC/HCT533) | | C _L = 15pF | 5 | 14 | - | - 1 | - | ns | |
| Disable Times | t _{TLH} , t _{THL} | C _L = 50pF | 4.5 | - | 30 | 38 | 45 | ns | |
| (HC/HCT533) | | C _L = 15pF | 5 | 12 | - | - | - | ns | |
| Enable and Disable Times | t _{PZH} , t _{PZL} , | C _L = 50pF | 4.5 | - | 35 | 44 | 53 | ns | |
| (HC/HCT563) | ^t PHZ, ^t PLZ | C _L = 15pF | 5 | 14 | - | - | - | ns | |
| Input Capacitance | Cl | - | - | - | 10 | 10 | 10 | pF | |
| Power Dissipation Capacitance (Notes 3, 4) | C _{PD} | - | 5 | 42 | - | - | - | pF | |

NOTES:

3. C_{PD} is used to determine the no-load dynamic power consumption, per latch.

4. P_D (total power per latch) = C_{PD} V_{CC}² f_i + Σ C_L V_{CC}² f_o where f_i = Input Frequency, f_o = Output Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms



NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

FIGURE 1. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

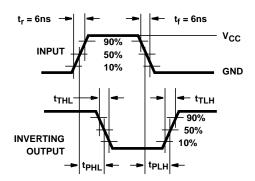
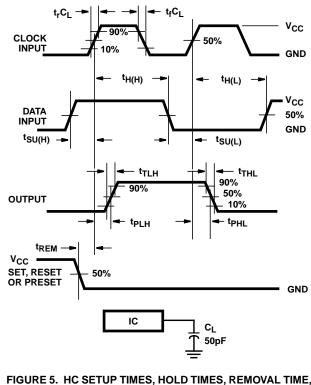
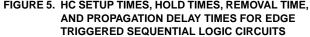
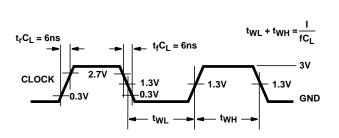


FIGURE 3. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

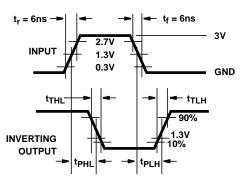


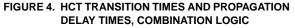


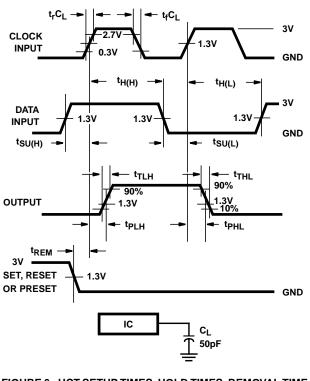


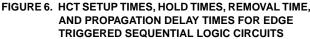
NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

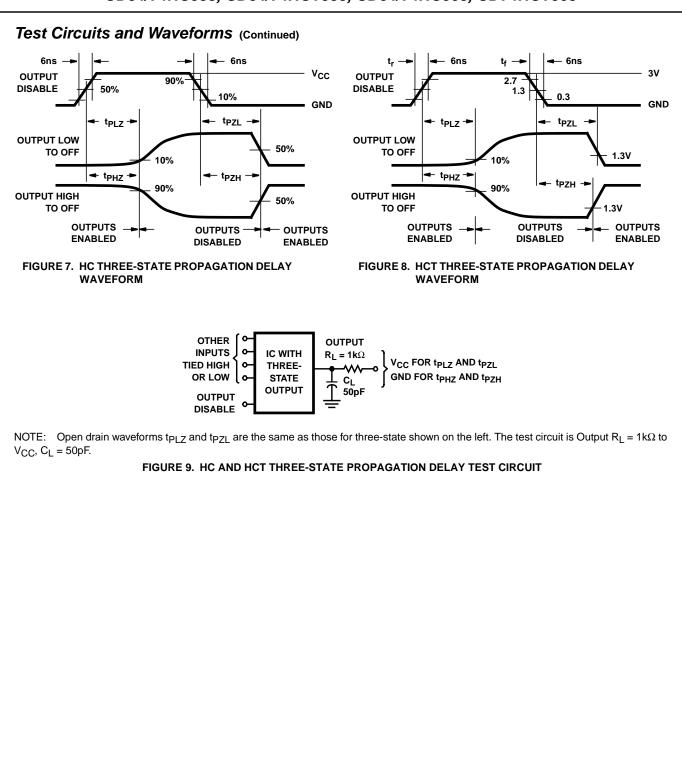
FIGURE 2. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH











TEXAS NSTRUMENTS www.ti.com

9-Oct-2007

PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/Ball Finish | MSL Peak Temp ⁽³⁾ |
|------------------|-----------------------|-----------------|--------------------|------|----------------|----------------------------|------------------|------------------------------|
| 5962-8606201RA | ACTIVE | CDIP | J | 20 | 1 | TBD | A42 SNPB | N / A for Pkg Type |
| 5962-8681301RA | ACTIVE | CDIP | J | 20 | 1 | TBD | A42 SNPB | N / A for Pkg Type |
| CD54HC533F3A | ACTIVE | CDIP | J | 20 | 1 | TBD | A42 SNPB | N / A for Pkg Type |
| CD54HC563F3A | ACTIVE | CDIP | J | 20 | 1 | TBD | A42 SNPB | N / A for Pkg Type |
| CD54HCT533F3A | ACTIVE | CDIP | J | 20 | 1 | TBD | A42 SNPB | N / A for Pkg Type |
| CD74HC533E | ACTIVE | PDIP | Ν | 20 | 20 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type |
| CD74HC533EE4 | ACTIVE | PDIP | Ν | 20 | 20 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type |
| CD74HC563E | ACTIVE | PDIP | Ν | 20 | 20 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type |
| CD74HC563EE4 | ACTIVE | PDIP | Ν | 20 | 20 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type |
| CD74HC563M | ACTIVE | SOIC | DW | 20 | 25 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HC563ME4 | ACTIVE | SOIC | DW | 20 | 25 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HC563MG4 | ACTIVE | SOIC | DW | 20 | 25 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HCT533E | ACTIVE | PDIP | Ν | 20 | 20 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type |
| CD74HCT533EE4 | ACTIVE | PDIP | Ν | 20 | 20 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type |
| CD74HCT563E | ACTIVE | PDIP | Ν | 20 | 20 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type |
| CD74HCT563EE4 | ACTIVE | PDIP | Ν | 20 | 20 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type |
| CD74HCT563M | ACTIVE | SOIC | DW | 20 | 25 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HCT563ME4 | ACTIVE | SOIC | DW | 20 | 25 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HCT563MG4 | ACTIVE | SOIC | DW | 20 | 25 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame



retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AC.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



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